

Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.56 \text{ V}$ at $I_F = 5 \text{ A}$





	-
PIN 1 O	PIN 2
PIN 3 O	

PRIMARY CHARACTERISTICS			
I _{F(AV)}	2 x 15 A		
V_{RRM}	150 V		
I _{FSM}	140 A		
V _F at I _F = 15 A	0.71 V		
T _J max.	150 °C		
Package	ITO-220AB		
Diode variations	Dual common cathode		

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

· High efficiency operation

• Solder bath temperature 275 °C max. 10 s, per JESD 22-B106

· Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

HALOGEN FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VF30150C	UNIT
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	30	^
	per diode		15	A
Peak forward surge current 8.3 ms single half superimposed on rated load	sine-wave	I _{FSM}	140	А
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs
Isolation voltage from terminal to heatsink t =	1 min	V _{AC}	1500	V
Operating junction and storage temperature ra	inge	T _J , T _{STG}	-55 to +150	°C



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	- V _F ⁽¹⁾	0.72	-	V	
	I _F = 7.5 A			0.81	-		
	I _F = 15 A			1.11	1.36		
	I _F = 5 A	T _A = 125 °C		0.56	-		
	I _F = 7.5 A			0.61	-		
	I _F = 15 A			0.71	0.79		
Reverse current per diode	I Vp = 100 V -	T _A = 25 °C	I _R ⁽²⁾	1.5	1	μΑ	
		T _A = 125 °C		2.0	-	mA	
	V _R = 150 V	T _A = 25 °C		-	200	μΑ	
	v _R = 150 v	T _A = 125 °C		4	20	mA	

Notes

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	SYMBOL VF30150C		
Typical thermal resistance per diode	$R_{ heta JC}$	4.5	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	VF30150C-M3/4W	1.75	4W	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

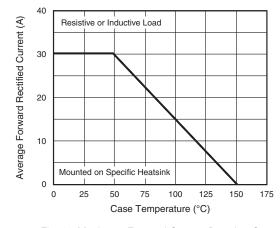


Fig. 1 - Maximum Forward Current Derating Curve

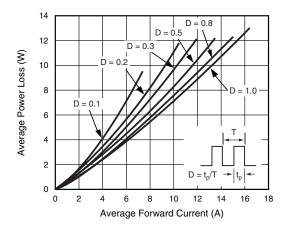


Fig. 2 - Forward Power Dissipation Characteristics

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle



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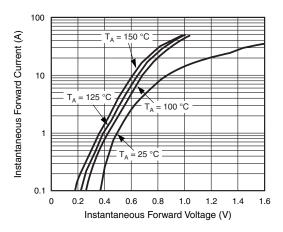


Fig. 3 - Typical Instantaneous Forward Characteristics

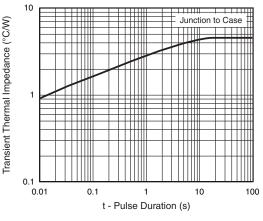


Fig. 5 - Typical Transient Thermal Impedance

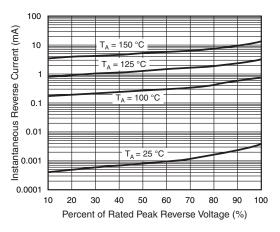


Fig. 4 - Typical Reverse Characteristics

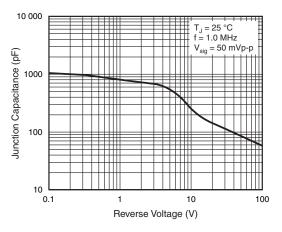
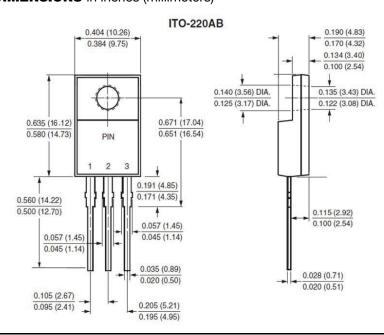


Fig. 6 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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